# T.E. ExTC- Sem-VI-Digitul Tel.

#### Date: > 11 16/14.

		(3 Hours) [Total Marks: 100	
N.B	(2) (3)		
1.	(b) (c)	Explain different transmission systems used in Telephony.  Explain Grade of service (GOS) with respect to Traffic analysis.  What is the significance of ATM adaptation layer.  Draw the 'ISDN' Architecture.	5 5 5
2.	(b)	Explain the concept of common control in crossbar switching system.  Compare single stage and multistage space division switching system.  Explain principle of Time slot Interchange (TSI) switch	10 10
3.	(a)	Explain user level and Network level signalling in ISDN.  Describe multi protocol label switching in detail.	10 10
4.		Explain in detail ISDN Data link layer protocol Explain in detail signalling system No. 7 elements.	10 10
5.		Draw ATM cell format and explain any one ATM application in detail.  What is Resource Reservation Protocol (RSVP)? Explain in detail.	10 10
	(b)	Explain what is wireless in Local Loop (WLL).  Compare features of ATM over frame Relay.  Explain Time Assigned speech Interpolation (TASI) w.r.t. lost call returned system.	5 10
7.	Writ	e short notes on:  (a) ISDN channels  (b) H. 323 protocol suite for VoIP.  (c) ATM protocol architecture.	6 7 7

(3 Hours)

[Total Marks: 100

N.B.: 1. Q. No.1 is compulsory

- 2. Answer any 4 of the remaining 6 questions
- 3. Figures to the right indicate the marks
- 4. Assume suitable data, if necessary and state them clearly

#### Q.1. Answer any 4 questions from the given questions:

a. Consider the two fuzzy sets

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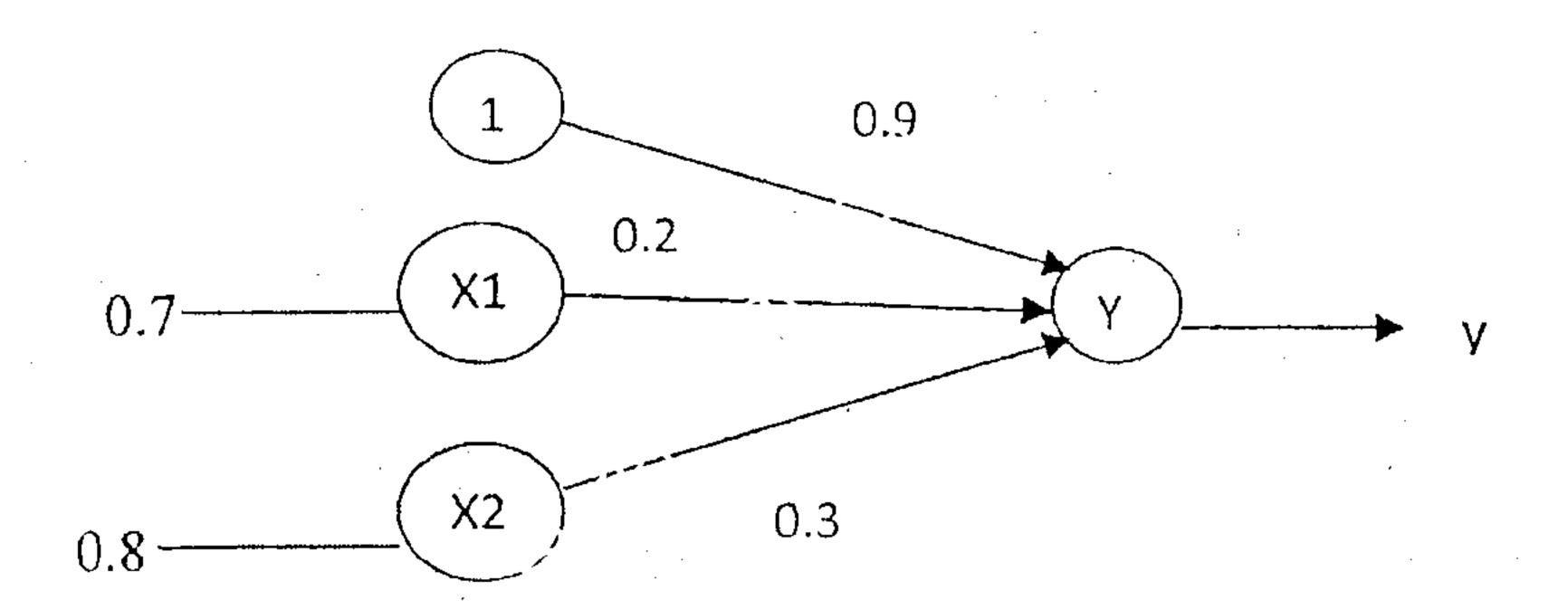
$$\hat{A} = \left\{ \frac{0.35}{0.7} + \frac{0.625}{0.725} + \frac{0.256}{0.75} \right\}$$

$$\stackrel{B}{\sim} = \left\{ \frac{0.95}{0.7} + \frac{0.815}{0.725} + \frac{0.67}{0.75} \right\}$$

Using Zadeh's notation, express the fuzzy sets as  $\lambda$ -cut set for  $\lambda = 0.8$  for the following operation:

$$A \cup B$$

- b. Explain fuzzy graph and fuzzy matrix with an example.
  - Write any three differences between supervised and unsupervised learning. 5
- d. Calculate the output of the neuron Y for the net given below. Use binary and bipolar sigmoidal activation functions.



- e. State any two applications of Kohonen self-organizing map.
- f. What is the necessity of de-fuzzification process.

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Q.2.a. Explain any 4 the membership functions.

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b. Three fuzzy sets are defined as follows:

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$$\stackrel{A}{\sim} = \left\{ \frac{0.1}{30} + \frac{0.2}{60} + \frac{0.3}{90} + \frac{0.4}{120} \right\}$$

$$\stackrel{B}{\sim} = \left\{ \frac{1}{1} + \frac{0.2}{2} + \frac{0.5}{3} + \frac{0.7}{4} + \frac{0.3}{5} + \frac{0}{6} \right\}$$

$$\stackrel{c}{\sim} = \left\{ \frac{0.33}{100} + \frac{0.65}{200} + \frac{0.92}{300} + \frac{0.21}{400} \right\}$$

Find the following:

(a) 
$$\stackrel{R}{\sim} = \stackrel{A}{\sim} X \stackrel{B}{\sim}$$

(b) 
$$\stackrel{S}{\sim} = \stackrel{B}{\sim} X \stackrel{C}{\sim}$$

(c) 
$$\tilde{z} = \tilde{z} \circ \tilde{s}$$
 using  $max - min composition$ 

- (d)  $\tilde{z} = \tilde{z} \circ \tilde{z}$  using max product composition
- Q.3.a. Describe simulated annealing. Explain Boltzmann machine with training phase. 10
  - b. Draw and explain radial basis function neural network for:

10

- i) Function approximation
- ii) Classification.
- Q.4.a. Find the weights required to perform the following classification using

  Perceptron network. The vectors (1, 1, 1, 1) and (-1, 1,-1,-1) are belonging to the class with target output 1 and vectors (1, 1, 1,-1) and (1,-1,-1, 1) are belonging to the class with target output 0. Assume learning rate to be 1 and initial weights to be zero. (calculate upto three epochs)
  - b. List the limitations of Perceptron.

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Q.5.a.	With a neat diagram, explain Kohonen Self organizing maps and list its important features.	10
b.	What are discrete Hopfield networks and mention any two applications of the same.	10
Q.6.a.	Explain the operation of the fuzzy logic control with process inference block.	8
ъ.	Write about Genetic algorithm and give any one application	8
c.	Explain the delta learning rule.	4
Q.7.	<ul> <li>Write notes on any two:</li> <li>a) Brain – state –in- a- box model</li> <li>b) Adaptive neuro-fuzzy information systems (ANFIS)</li> <li>c) Stopping criteria for neural network training</li> <li>d) Mamdani and Takagi architecture</li> </ul>	20

T. E. EXTC - Micro Bleehoonics - 11/6/14. Sem-VI.

(3 Hours)

QP Code: MV-18312

[Total Marks: 80

N.B. :	(2)	Question No. 1 is compulsory.  Attempt any four questions from the remaining six questions.  Assume suitable data wherever necessary.	
1. S	(a) (b) (c) (d)	List different types of resistors used in monolithic Integrated Circuit. Draw cross-section of one of them. In N-channel E-MOSFET $V_{GS}=5$ V, $V_{DS}=5$ V, $V_{TO}=1.0$ V, $V_{BS}=0$ V, $W=10$ $\mu m$ , $L=5$ $\mu m$ , channel length modulation factor $\lambda=0.02$ V <sup>-1</sup> and $\mu n$ $C_{OX}=100$ $\mu A/V^2$ . Calculate its drain current. Draw cross-section for all possible configuration of monolithic planar diode. Which one is the best and why? List advantages of MOSFET technlogy over Bipolar technology. Draw and explain the doping profile obtained from constant impurity source diffusion and limited impurity source diffusion.	20
2. (	b) W	iscuss in detail different parasitic effects in MOSFETS.  /hat are different types of scaling? Explain them in detail with their respective dvantages and disadvantages.	10
3. (	b) E:	Ith neat diagram explain Czochralski method for single crystal growth. xplain in detail the fabrication sequence of BJT with cross section of each steplong with mask used. Explain the neeed for epitaxial layer.	10
4. (	ar b) D	In the help of neat diagrams, explain the process of ion implantation. What we the advantages of ion implantation process over diffusion process. The raw circuit diagram, stick diagram of CMOS inverter. Also draw layout of CMOS exerter using lambda rules ( $\lambda$ ). Take size of PMOS as twice the size of NMOS.	
,	b) H	nplement following function:—  y = AB + C (D + E) using  (i) Depletion load NMOS technology  (ii) Saturated load NMOS technology  (iii) CMOS technology.  ow capacitors are fabricated in MOS and BJT technology. Draw cross-sections feach structure	10

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6. (a) Calculate thereshold voltage at VSB = 0 V for a polysilicon gate n-channel MOS 10 transister with following parameters:—

Substrate doping density  $N_A = 10^{16}$  cm<sup>-3</sup>,

Polysilicon gate doping density  $N_D = 2 \cdot 10^{20}$  cm<sup>-3</sup>,

Gate oxide thickness tox = 500 A°, and

Oxide-interface fixed charge density  $N_{\rm OX} = 4 \times 10^{10}$  cm<sup>-2</sup>,

Instrinsic concentration  $n_i = 1.45 \times 10^{10} \text{ cm}^{-3}$ ,  $\frac{kT}{q} = 26 \text{ mV}$ 

$$\epsilon_0 = 8.85 \times 10^{-14} \text{ F/cm}, \ \epsilon_{si} = 11.7 \ \epsilon_0, \ \epsilon_{ox} = 3.97 \ \epsilon_0.$$
  $q = 1.6 \times 10^{-19} \text{ C}.$ 

(b) For resistive load NMOS inverter

 $R_L=20~K,~V_{TO}=1V,~\mu_n~C_{OX}=100~\mu\text{A}/V^2,$   $W=20~\mu\text{m},~L=1\mu\text{m},~\text{Find}~V_{OH},~V_{OL},~V_{IL}~\text{and}~V_{IH}.$  Assume  $V_{DD}=5~V.$ 

- 7 Write short notes on any three :-
  - (a) TTL NAND gate
  - (b) Buried and Butted Contact
  - (c) Isolation techniques used in BJT technology
  - (d) IC Cross-overs.

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### T.E. ExTC-Radar Engg. Sem VI (Eleehive) - 11/6/14.

	(3 Hours) [ Total Marks: 10	00
	<ul> <li>N. B.: (1) Question No. 1 is compulsory.</li> <li>(2) Attempt any four questions out of remaining six questions.</li> <li>(3) Assume suitable data wherever necessary.</li> </ul>	
1.	<ul> <li>(a) Explain the factors which govern the pulse repetition frequency.</li> <li>(b) Explain briefly the factors that influence bandwidth of radar.</li> <li>(c) Explain Doppler filter banks.</li> <li>(d) Explain in brief displays used in radar system.</li> </ul>	20
2.	$\mathcal{C}$	10 10
3.	<b>.</b>	10 10
1.	Discuss the various scanning techniques and tracking mechanisms.	10 10
5.		10 10
5.	(i) sphere (ii) Rod and (iii) cone.	10 10
7.	Write short note on any three:  (a) FM-CW altimeters (b) Working of Hybrid Tee and circulator as duplexer in Radar (c) Phased array Radar (d) Staggered PRF's.	20

## TE CEXTC) REU, SEMITT

3/05/114

(3 Hours)

QP Code: MV-18092 [Total Marks: 100

Q1. Is compulsory

Solve any four out of remaining

Q1.

A. Draw and explain read write bus cycle of 8086 in maximum mode. (5 marks)

B. What are advantages of memory segmentation in 8086?

(5 marks)

C. Write features of PIC-18.

(5 marks)

D. Explain PIC 18 data memory organization.

(5 marks)

Q2. A

Draw and interface diagram of 8086 microprocessor and 8087 NDP, also explain various interface signals and co-processor working with host processor. (10 marks)

Q2. B

Design a system using 8086 in minimum mode with following specifications

- 1. 8086 operating on 5 MHz
- 2. 16 KB RAM using 8 KB device with starting address of 10000.
- 3. 16 KB EPROM using 8 KB device.

(10 marks)

- Q3. A. What is string addressing mode of 8086. Explain string instructions of 8086. (10 marks)
- Q3 B. Draw and explain interfacing of 8086(maximum mode) and 8259 in single mode. (10 marks)
- Q4.A Write assembly language programme for 8086 to exchange a 1 KB block of data from memory location 40000 to 50000. (10 marks)
- Q4 B Explain following instructions of PIC18
  - 1. ANDLW k 2. BTFSC f,b 3. SUBLW k 4. DECFSZ f,d 5. RRF f,d

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Q5. A Connect four 7-segment displays to PiC18 and write assembly language programme to display

'5' on LSB of display. (10 marks)

Q5 B Write instruction format of PIC 18 instructions. (10 marks)

Q6A. Draw and explain interfacing of 8086 and 8257 DMA controller. (10 marks)

Q6 B Explain I/O synchronization methods of PIC18. (10 marks)

Q7. A. Explain interrupt structure of 8086.

(10 marks)

Q7 B. Explain assembler directives of 8086.

(10 marks)

[Total Marks: 100 (3 Hours)

N	R	(1)	Question	$N_0$ 1	10	compulsory.
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N. E	(	<ol> <li>Question No. 1 is compulsory.</li> <li>Attempt any four questions from the remaining six questions.</li> <li>Assume suitable data if necessary, but justify the same.</li> </ol>	
1.	(a)	What do you mean by isotropic, omnidrectional and directional antenna. Draw	5
	( <b>h</b> )	radiation pattern and give example of each antenna.	5
	` '	Describe the concept of near field and far field regions.  Explain with the help of a diagram, how a reflector helps in increasing the directivity of an antenna.	5
	(d)	Differentiate between broadside and end fire array.	5
2.	(a)	Derive expressions for electric and magntic fields in far field region of an infitesimal dipole.	10
	(b)	State and derive FRISS transmission equation. What is its significance in wireless communication.	10
3.	(a)	Explain the working principle of a folded dipole antenna. What are its advantages and applications.	10
	(b)	Derive an expression of array factor of a uniform linear array of n elements. Also find the expressions for the position of principle maxima, nulls and s'econdary maximas.	10
4.	(a)	Explain pattern multiplication. Draw the radiation pattern of an array of two half wave dipoles which are fed in phase and placed along a line at $\lambda/2$ distance apart.	10
	(b)		10
5.	(a)	How gain of an antenna is different from directivity. Explain a method used to measure the gain of an antenna.	10
	(b)	Explain the mechanism of ionospheric propagation. Also define the terms - Critical frequency, virtual height, maximum usable frequency and skip distance.	1Û
6.	(a)	Explain the working principle of a Yagi-Uda antenna array. What are its advantages, disadvantages and applications.	10
	(b)	Describe parabolic reflector antenna and its applications at microwave frequency. What are the various feeding methods used in parabolic reflector antennas.	10

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QP Code: MV-18133

- 7. Write short notes on :-
  - (a) Ground wave propagation.
  - (b) Log periodic antenna.
  - (c) Horn antenna.
  - (d) Polarization.

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# Digital Communication SEM VI 26105/14' EXTC

	(3 Hours) [ Tot	al Marks:	100
	<ul> <li>N. B.: (1) Question No. 1 is compulsory.</li> <li>(2) Attempt any four question from remaining six questions.</li> <li>(3) Assume suitable data if necessary.</li> </ul>		
<b>l</b> .	1. (a) Explain the function of a bit synchromizer.		5
	(b) Distinguish between a matched filter and co-rrelator.		5
	(c) Explain line codes and their characterstics.		5
	(d) Explain shanon-Hartley Theorem on channel capacity.		5
2.	<ol> <li>(a) Explain M-ary FSK Transmitter and Receiver with neat block diagram</li> <li>(b) A Gaussian channel has 2 MHz bandwidth. Calculate the channel capa signal to Noise Spectral density ratio is 10<sup>4</sup>. Also calculate the information rate.</li> </ol>	acity if the	10 5
	(c) Explain systamatic and non-systamatic error correcting codes.		5
3.	3. (a) Draw and explain the block diagram of non-offect QPSK transmitter an	d receiver.	10
	Also draw output waveform.  (b) The generator polymonial for a (7, 4) cyclic code is		1 Λ
	(b) The generator polymonial for a (7, 4) cyclic (30dc is $g(x) = 1 + x^2 + x^3$		10
	<ul><li>(i) Draw the block diagram of Encoder and syndram calculator.</li><li>(ii) Find the code polynimal of 0110.</li></ul>		•
4.	4. (a) A 1/3 rate, k=3 convolutional encoder can be described by the impuls of the path given by:- $g_1 = 101, g_2 = 110, g_3 = 011$	e response	10
	<ul> <li>(i) Draw the block diagram of encoder.</li> <li>(ii) Draw the code tree and state diagram. Hence find out output if the input to the encoder is 11010.</li> </ul>	t sequence	
	(b) Draw the signal space diagram of 16 QASK and calculate the Euclidean	an distance	10
	and compare it with 16-PSK.		
5.	5. (a) Define entropy and Information rate. A source emits symbols with probabilities	the given	10
	0.2, 0.25, 0.15, 0.15, 0.05, 0.1		
	Calculate:		
	(1) Entropy of source		
	(2) Huffman code		
	(3) Code Efficiency.		
	(b) What is equalization. Explain with block diagram a tapped delay line	equilizer.	10

6. (a) Consider a (7, 4) code whose generator matrix is

$$G = \begin{bmatrix} 1 & 1 & 1 & 1 & 0 & 0 & 0 \\ 1 & 0 & 1 & 0 & 1 & 0 & 0 \\ 0 & 1 & 1 & 0 & 0 & 1 & 0 \\ 1 & 1 & 0 & 0 & 0 & 0 & 1 \end{bmatrix}$$

- (i) Find the code word for (i) 1101 (ii) 1001
- (ii) Find out the parity check matrix
- (iii) What is the error detecting and correcting capability of the code.
- (b) Define the expression for

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- (1) Impulse response
- (2) Propability of error of a matched filter.
- 7. Write short notes an (any two):

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- (1) Eye pattern
- (2) ISI and ICI
- (3) MSK.

## T.E. Sem VI IESTR -5/6/14. (EXTC)

		(2 Hours) [ Total Marks: 50	•
N.B.	(2)	Question No. 1 is compulsory.  Attempt any four questions from remaining six questions.  All questions carry equal marks.	
1.	(a) (b) (c)	Short notes on any two of the following questions:-  Explain Taylor's Scientific Management Theory.  TRAI regulation.  Broadband Policy.  Effective communication in enterprises.	10
2.		Explain the Masslow's need hierarchy. Compare it with Maintenance Motivation theory? Discuss Foreign Exhange Control.	5
3.		Explain features of "Monopoly" and "Perfect Competition". Compare them.  Explain the objective of market research and its process.	5
4.	•	Explain guidelines for obtaining License for providing Direct to Home (D.H.T.) Discuss multiple credit creation. Who are the beneficiaries of this creation?	5
5.	\ /	Explain price discrimination with suitable example.  How does the basic concept of management are applicable to all kinds of business?	5
6.	, ,	How does the government project international trade? Explain planning with suiable example.	5 5
7.	` /	Compare Direct and Indirect taxes.  Give distinction between Balance of trade and Balance of payments.	5

## TECEXTO Sem II (Rev course) television & video Engineering

3 Hours)	•	[ Total Marks
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N.B	`	<ol> <li>Question No.1 is compulsory.</li> <li>Out of remaining questions, attempt any four questions.</li> </ol>	::
1.	(b)	How a light image is converted into electrical signal using photoconduction.	5 5 5
2.	(a) (b)	Draw the block diagram of a monochrome TV transmitter and explain the working. What is the need of scanning? Explain progressive scanning in detail.	10 10
3.	(a) (b)	components in details.	10 10
4.	(a) (b)	Explain PAL coder system? How phase error are cancelled in PAL system? What is EIA test pattern? Draw and explain EIA pattern with utility.	10 10
5.		Draw and explain vidicon camera tube what is meant by dark current in vidicon? List the important equipments needed for troubleshooting a TV receiver. Suggest the common procedure to be followed while troubleshooting a TV receiver.	
6.	(a) (b)	Draw neat diagram to indicate sync separate section in TV system and explain it. With the help of neat diagram explain the functioning of cable television.	10 10
7.		ite short notes on:—  (a) Interlaced scanning  (b) HDTV  (c) AGC  (d) Multicasting	20